



IEC TS 62804-1:2015

Photovoltaic (PV) Modules - Test Methods for the detection of potential-induced degradation

Part 1: Crystalline silicone
Confirmation of test results

File Ref.: 10004/2022-40133

Applicant: Changzhou EGing Photovoltaic Technology Co., Ltd.
No. 18 Jinwu Road, 213213 Jintan City, China

Product: Crystalline silicon Photovoltaic (PV)-Modules

Type: BM) EG-XXXM72-HL/BF-DG BN) EG-XXXM60-HL/BF-DG
BQ) EG-XXXM54-HL/BF-DG

XXX in the type replaces the power in watt and can be any number between:

510 - 550 for BM), 425 - 465, BN),
385 - 425 for BO)

Manufacturer: Changzhou EGing Photovoltaic Technology Co., Ltd.

Standard: IEC TS 62804-1:2015

Test conditions

Testing time: 96 h
Chamber temperature: 85°C
Relative humidity: 85 %
Potential to ground: +/- 1500 V

Pass criteria

Power Degradation: < 5%
Dry Insulation Resistance: > 40 MΩm²
Wet Insulation Resistance: > 40 MΩm²
Visual Inspection: No findings

